

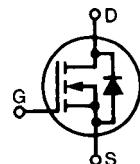
HiPerFET™ Power MOSFETs Q-Class

N-Channel Enhancement Mode
Avalanche Rated, High dv/dt, Low t_{rr}
Low Gate Charge and Capacitances

Preliminary data

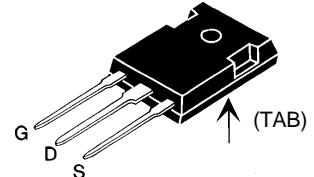
IXFH 52N30Q
IXFK 52N30Q
IXFT 52N30Q

$V_{DSS} = 300$ V
 $I_{D25} = 52$ A
 $R_{DS(on)} = 60$ mΩ
 $t_{rr} \leq 250$ ns

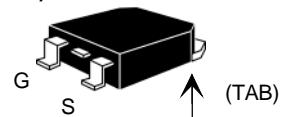


| Symbol | Test Conditions | Maximum Ratings | | |
|---------------|--|----------------------------|----------------------------|--|
| V_{DSS} | $T_J = 25^\circ\text{C}$ to 150°C | 300 | V | |
| V_{DGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1$ MΩ | 300 | V | |
| V_{GS} | Continuous | ±20 | V | |
| V_{GSM} | Transient | ±30 | V | |
| I_{D25} | $T_c = 25^\circ\text{C}$, Chip capability | 52 | A | |
| I_{DM} | $T_c = 25^\circ\text{C}$, pulse width limited by T_{JM} | 208 | A | |
| I_{AR} | $T_c = 25^\circ\text{C}$ | 52 | A | |
| E_{AR} | $T_c = 25^\circ\text{C}$ | 30 | mJ | |
| E_{AS} | $T_c = 25^\circ\text{C}$ | 1.5 | J | |
| dv/dt | $I_s \leq I_{DM}$, $di/dt \leq 100$ A/μs, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$, $R_G = 2$ Ω | 5 | V/ns | |
| P_D | $T_c = 25^\circ\text{C}$ | 360 | W | |
| T_J | | -55 ... +150 | °C | |
| T_{JM} | | 150 | °C | |
| T_{stg} | | -55 ... +150 | °C | |
| T_L | 1.6 mm (0.063 in) from case for 10 s | 300 | °C | |
| M_d | Mounting torque | TO-247 TO-264 | 1.13/10 0.9/6 Nm/lb.in. | |
| Weight | | TO-247 TO-264 TO-268 | 6 10 4 g | |

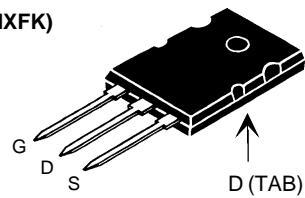
TO-247 AD (IXFH)



TO-268 (D3) (IXFT)



TO-264 AA (IXFK)



G = Gate
S = Source

TAB = Drain

| Symbol | Test Conditions | Characteristic Values | | |
|--------------|---|--|---------|----------|
| | | ($T_J = 25^\circ\text{C}$, unless otherwise specified) | min. | typ. |
| V_{DSS} | $V_{GS} = 0$ V, $I_D = 1$ mA | 300 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 4$ mA | 2 | 4 | V |
| I_{GSS} | $V_{GS} = \pm 20$ V _{DC} , $V_{DS} = 0$ | | ±200 | nA |
| I_{DSS} | $V_{DS} = V_{DSS}$ $V_{GS} = 0$ V | $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ | 50 1 | μA mA |
| $R_{DS(on)}$ | $V_{GS} = 10$ V, $I_D = 0.5 \cdot I_{D25}$ Pulse test, $t \leq 300$ μs, duty cycle d ≤ 2 % | | 60 | mΩ |

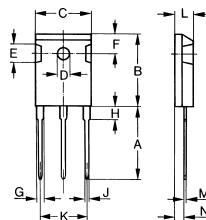
Features

- Low gate charge
- International standard packages
- Epoxy meet UL94V-0, flammability classification
- Low $R_{DS(on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Avalanche energy and current rated
- Fast intrinsic Rectifier

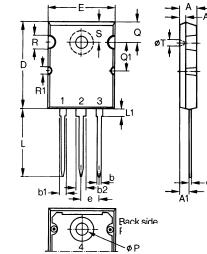
Advantages

- Easy to mount
- Space savings
- High power density

| Symbol | Test Conditions | Characteristic Values | | |
|---|--|--|------|------|
| | | ($T_j = 25^\circ\text{C}$, unless otherwise specified) | min. | typ. |
| g_{fs} | $V_{DS} = 10 \text{ V}; I_D = 0.5 \cdot I_{D25}$, pulse test | 22 | 35 | S |
| C_{iss} C_{oss} C_{rss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$ | 5300 | pF | |
| | | 1010 | pF | |
| | | 200 | pF | |
| $t_{d(on)}$ t_r $t_{d(off)}$ t_f | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ $R_G = 1.5 \Omega$ (External), | 27 | ns | |
| | | 60 | ns | |
| | | 80 | ns | |
| | | 25 | ns | |
| $Q_{g(on)}$ Q_{gs} Q_{gd} | $V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 0.5 \cdot I_{D25}$ | 150 | nC | |
| | | 34 | nC | |
| | | 75 | nC | |
| R_{thJC} | | | 0.35 | K/W |
| R_{thCK} | TO-247 | 0.25 | | K/W |
| | TO-264 | 0.15 | | K/W |

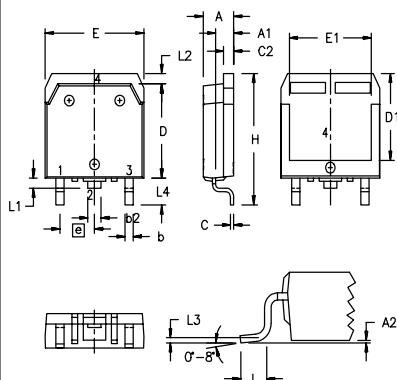
TO-247 AD (IXFH) Outline


| Dim. | Millimeter Min. | Max. | Inches Min. | Max. |
|------|--------------------|-------|----------------|-------|
| A | 19.81 | 20.32 | 0.780 | 0.800 |
| B | 20.80 | 21.46 | 0.819 | 0.845 |
| C | 15.75 | 16.26 | 0.610 | 0.640 |
| D | 3.55 | 3.65 | 0.140 | 0.144 |
| E | 4.32 | 5.49 | 0.170 | 0.216 |
| F | 5.4 | 6.2 | 0.212 | 0.244 |
| G | 1.65 | 2.13 | 0.065 | 0.084 |
| H | - | 4.5 | - | 0.177 |
| J | 1.0 | 1.4 | 0.040 | 0.055 |
| K | 10.8 | 11.0 | 0.426 | 0.433 |
| L | 4.7 | 5.3 | 0.185 | 0.209 |
| M | 0.4 | 0.8 | 0.016 | 0.031 |
| N | 1.5 | 2.49 | 0.087 | 0.102 |

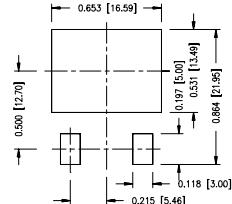
TO-264 AA Outline

Source-Drain Diode
Characteristic Values

($T_j = 25^\circ\text{C}$, unless otherwise specified)

| Symbol | Test Conditions | min. | typ. | max. |
|----------------------------------|---|------|------|---------------|
| I_s | $V_{GS} = 0 \text{ V}$ | | 52 | A |
| I_{SM} | Repetitive; pulse width limited by T_{JM} | | 208 | A |
| V_{SD} | $I_F = I_s, V_{GS} = 0 \text{ V}$, Pulse test, $t \leq 300 \mu\text{s}$, duty cycle $d \leq 2\%$ | | 1.5 | V |
| t_{rr} Q_{RM} I_{RM} | $I_F = I_s - di/dt = 100 \text{ A}/\mu\text{s}, V_R = 100 \text{ V}$ | 1 | 250 | ns |
| | | 8 | | μC |
| | | | | A |

TO-268AA (D³ PAK)


| Dim. | Millimeter Min. | Max. | Inches Min. | Max. |
|----------------|--------------------|-------|----------------|------|
| A | 4.9 | 5.1 | .193 | .201 |
| A ₁ | 2.7 | 2.9 | .106 | .114 |
| A ₂ | .02 | .25 | .001 | .010 |
| b | 1.15 | 1.45 | .045 | .057 |
| b ₂ | 1.9 | 2.1 | .75 | .83 |
| C | .4 | .65 | .016 | .026 |
| D | 13.80 | 14.00 | .543 | .551 |
| E | 15.85 | 16.05 | .624 | .632 |
| E ₁ | 13.3 | 13.6 | .524 | .535 |
| e | 5.45 BSC | | .215 BSC | |
| H | 18.70 | 19.10 | .736 | .752 |
| L | 2.40 | 2.70 | .094 | .106 |
| L1 | 1.20 | 1.40 | .047 | .055 |
| L2 | 1.00 | 1.15 | .039 | .045 |
| L3 | 0.25 BSC | | .010 BSC | |
| L4 | 3.80 | 4.10 | .150 | .161 |

Min. Recommended Footprint




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